Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

1.188 inches

Mounting Facility Quantity:

1

## **Mounting Method:**

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.438 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, peak

**Current Rating Per Characteristic:** 

15.00 amperes source cutoff current outside diameter

## **Power Rating Per Characteristic:**

5.5 watts small-signal input power, common-collector peak

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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### Demilitarization:

No

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